



#### 30V N-Channel Enhancement Mode MOSFET

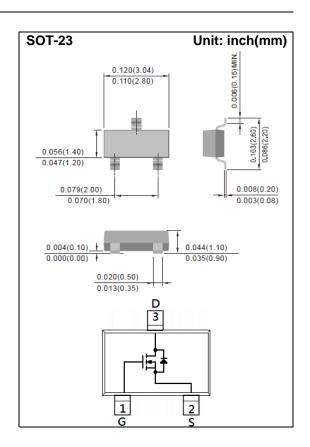
Voltage 30 V Current 4.4A

#### **Features**

- RDS(ON) , VGS@10V, ID@4.4A<48mΩ</li>
- RDS(ON) , VGS@4.5V, ID@2.8A<70mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for switch Load, PWM applications, and solid-state relays relay
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### **Mechanical Data**

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A06



## **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	4.4	Α
Pulsed Drain Current		I <sub>DM</sub>	17.6	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_{J}, T_{STG}$	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	100	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1.0	1.37	2.1	V
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4.4A	_	35	48	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =2.8A	-	51	70	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	-	0.01	1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	$Q_g$	\/ -45\/   -4.44	_	5.8	-	nC
Gate-Source Charge	$Q_gs$	$V_{DS}$ =15V, $I_{D}$ =4.4A, $V_{GS}$ =10V (Note 1,2)	-	1	-	
Gate-Drain Charge	$Q_{gd}$		-	1	-	
Input Capacitance	Ciss	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	235	-	pF
Output Capacitance	Coss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	36	-	
Reverse Transfer Capacitance	Crss		-	24	-	
Switching						
Turn-On Delay Time	td <sub>(on)</sub>	$V_{DD}$ =15V, $I_{D}$ =4.4A, $V_{GS}$ =10V, $R_{G}$ =6 $\Omega$ (Note 1.2)	_	3	-	
Turn-On Rise Time	tr		-	39	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	23	-	
Turn-Off Fall Time	tf		-	28	-	
Drain-Source Diode						
Maximum Continuous Drain-Source					1.5	А
Diode Forward Current	I <sub>S</sub>		-	_		
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.77	1.2	V

### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### **TYPICAL CHARACTERISTIC CURVES**

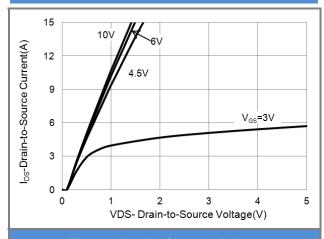
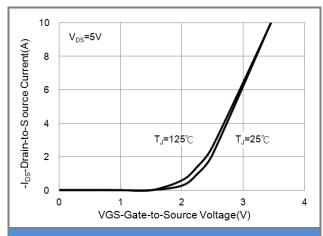


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

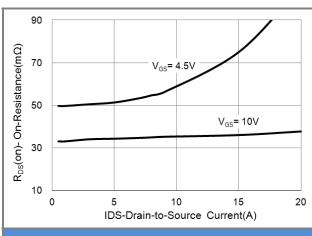


Fig.3 On-Resistance vs. Drain Current

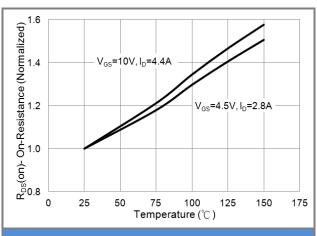
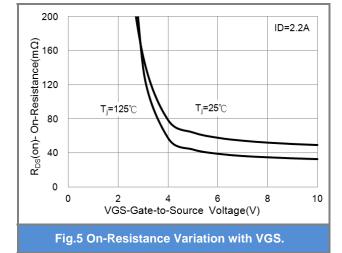


Fig.4 On-Resistance vs. Junction temperature



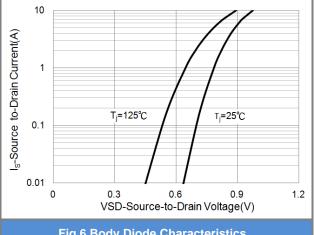


Fig.6 Body Diode Characteristics





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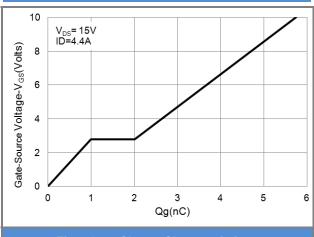


Fig.7 Gate-Charge Characteristics

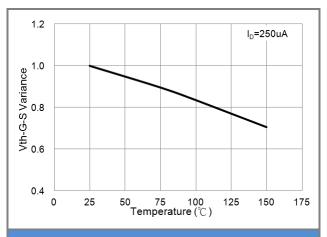
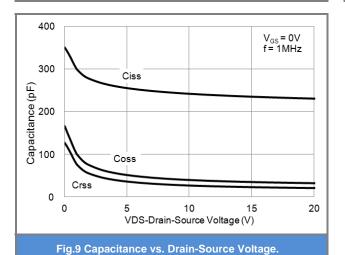


Fig.8 Threshold Voltage Variation with Temperature.



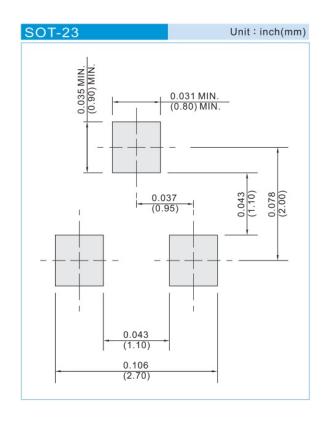




### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJA3406_R1_00001	SOT-23	3K pcs / 7" reel	A06	Halogen free
PJA3406_R2_00001	SOT-23	12K pcs / 13" reel	A06	Halogen free

### **MOUNTING PAD LAYOUT**







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